

Low frequency amplifier

QST4

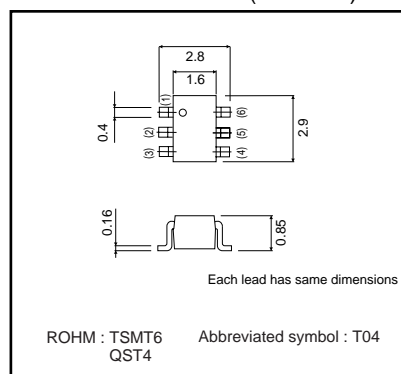
●Application

Low frequency amplifier
Driver

●Features

- 1) A collector current is large.
- 2) $V_{CE(sat)}$: max. -250mV
At $I_C = -1.5\text{A} / I_B = -30\text{mA}$

●External dimensions (Unit : mm)



●Absolute maximum ratings (Ta=25°C)

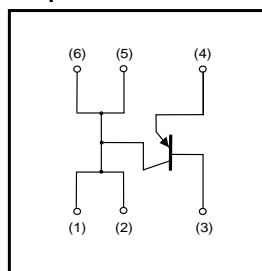
Parameter	Symbol	Limits	Unit
Collector-base voltage	V_{CB0}	-15	V
Collector-emitter voltage	V_{CE0}	-12	V
Emitter-base voltage	V_{EB0}	-6	V
Collector current	I_C	-3	A
	I_{CP}	-6	A ^{*1}
Power dissipation	P_C	500	mW ^{*2}
		1.25	W ^{*3}
Junction temperature	T_J	150	°C
Range of storage temperature	T_{stg}	-55 to +150	°C

*1 Single pulse, $P_w = 1\text{ms}$

*2 Each Terminal Mounted on a Recommended

*3 Mounted on a 25mm×25mm×1.0mm Ceramic substrate

●Equivalent circuit



●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Collector-base breakdown voltage	BV_{CB0}	-15	-	-	V	$I_C = -10\mu\text{A}$
Collector-emitter breakdown voltage	BV_{CE0}	-12	-	-	V	$I_C = -1\text{mA}$
Emitter-base breakdown voltage	BV_{EB0}	-6	-	-	V	$I_E = -10\mu\text{A}$
Collector cutoff current	I_{CB0}	-	-	-100	nA	$V_{CB} = -15\text{V}$
Emitter cutoff current	I_{EB0}	-	-	-100	nA	$V_{EB} = -6\text{V}$
Collector-emitter saturation voltage	$V_{CE(sat)}$	-	-120	-250	mV	$I_C = -1.5\text{A}, I_B = -30\text{mA}$
DC current gain	h_{FE}	270	-	680	-	$V_{CE} = -2\text{V}, I_C = -500\text{mA}^*$
Transition frequency	f_T	-	280	-	MHz	$V_{CE} = -2\text{V}, I_E = 500\text{mA}, f = 100\text{MHz}^*$
Collector output capacitance	C_{ob}	-	30	-	pF	$V_{CB} = -10\text{V}, I_E = 0\text{A}, f = 1\text{MHz}$

* Pulsed

Transistors

●Packaging specifications

Type	Package	Taping
	Code	TR
	Basic ordering unit (pieces)	3000
QST4		○

●Electrical characteristic curves

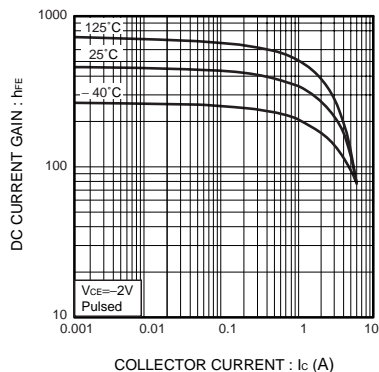


Fig.1. DC current gain vs. collector current

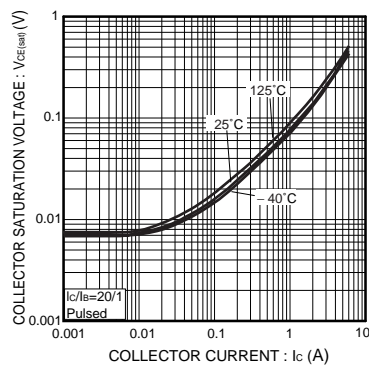


Fig.2. Collector-emitter saturation voltage vs. collector current

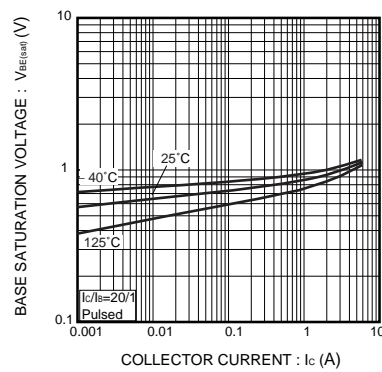


Fig.3. Base-emitter saturation voltage vs. collector current

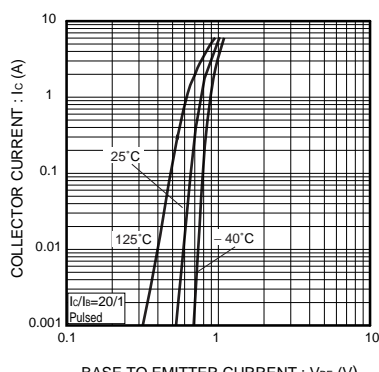


Fig.4. Grounded emitter propagation characteristics

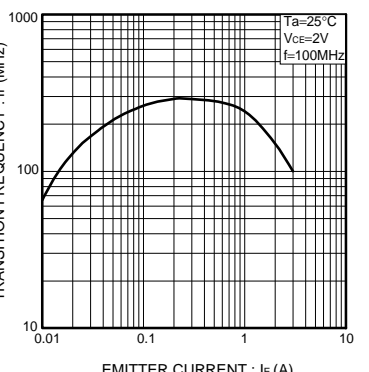


Fig.5. Gain bandwidth product vs. emitter current

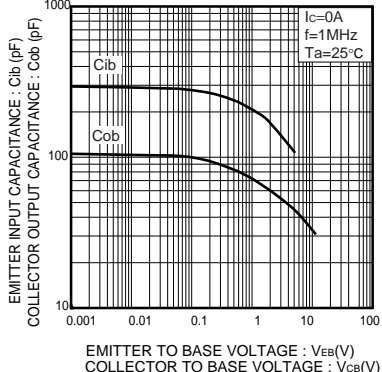


Fig.6. Collector output capacitance vs. collector-base voltage
Emitter input capacitance vs. emitter-base voltage

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